MSKSEMI 美森科













ESD

TSS

MOV

GDT

PIFD

L7812CV(MS)

Product specification





Three-terminal positive voltage regulator

FEATURES

Maximum Output current IOM: 1.5 A

Output voltage Vo:12V

Continuous total dissipation

P_D: 1.5 W (T_a = 25 °C) 15 W(T_c = 25 °C)

Reference News

PACKAGE OUTLINE		Marking
1 2 3	1.IN 2.GND 3.OUT	MSKSEMI L7812CV CHN MS**

ABSOLUTE MAXIMUM RATINGS (Operating temperature range applies unless otherwise specified)

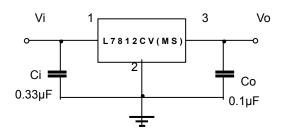
Parameter	Symbol	Value	Unit
Input Voltage	Vi	35	V
Thermal Resistance from Junction to Ambient	R _{θJA}	83.3	°C/W
Thermal Resistance from Junction to Case	$R_{ heta JC}$	8.3	°C/W
Operating Junction Temperature Range	T _{OPR}	0~+150	℃
Storage Temperature Range	T _{STG}	-55~+150	$^{\circ}$

ELECTRICAL CHARACTERISTICS AT SPECIFIED VIRTUAL JINCTION TEMPERATURE

(Vi=19V, Io=500mA,Ci=0.33 $\mu\text{F},$ Co=0.1 $\mu\text{F},$ unless otherwise specified)

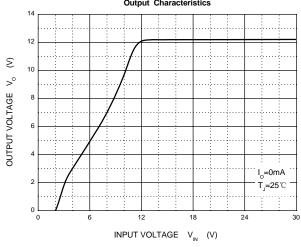
Parameter	Symbol	Test conditions		Min	Тур	Max	Unit
			25℃	11.5	12.0	12.5	V
Output voltage	Vo	Io= 5.0mA-1.0A, P≤15W 14.5V≤ V _i ≤27V	0-125℃	11.4	12	12.6	V
Load Regulation	ΔVο	14.5V≤ Vi ≤30V	25℃		10	240	mV
		16V≤V _i ≤22V	25℃		3	120	mV
Line regulation	ΔVο	I _O =5mA - 1.5A	25℃		12	240	mV
		I _O =250mA - 750mA	25℃		4	120	mV
Quiescent Current	Iq		25℃		4.3	8	mA
Quiescent Current Change	Δlq	5.0mA≤ I _O ≤1.0A	0-125℃			0.5	mA
Quiescent ourrent onlarige	Діч	14.5V ≤V _i ≤ 30V	0-125℃			1.0	mA
Output voltage drift	△Vo/△T	I _O =5mA	0-125℃		-1		mV/℃
Output Noise Voltage	V _N	f =10Hz to 100KHz	25℃		75		μV
Ripple Rejection	RR	f =120Hz, 15V≤ V _i ≤25V	0-125℃	55	71		dB
Dropout Voltage	V_d	I _O =1.0A	25℃		2		V
Output resistance	Ro	f = 1KHz	25℃		18		mΩ
Short Circuit Current	Isc		25℃		350		mA
Peak Current	lpk		25℃		2.2		Α

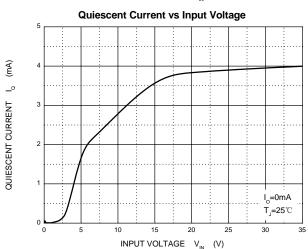
TYPICAL APPLICATION

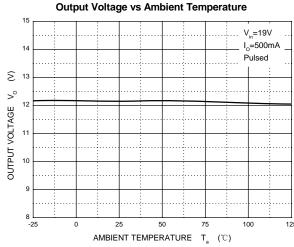


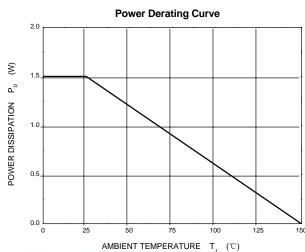


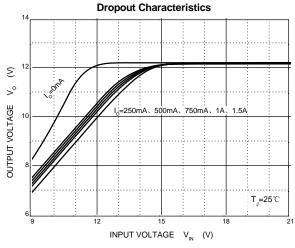
Typical Characterisitics

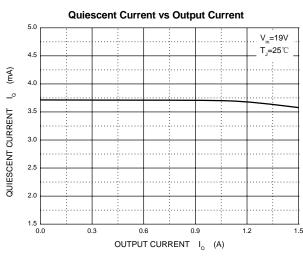


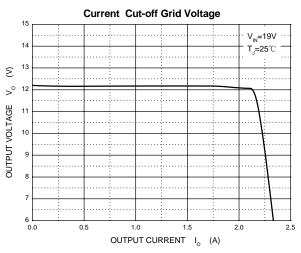






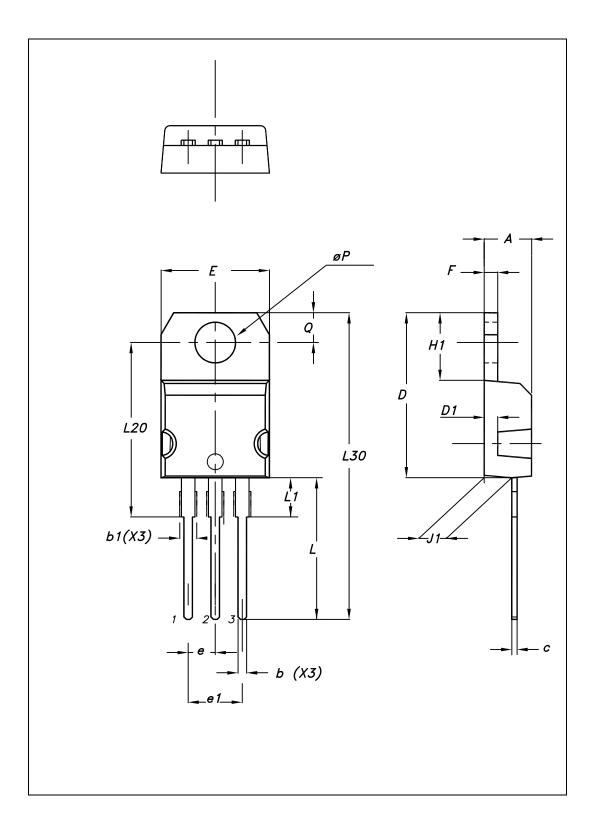








Package mechanical data





Package mechanical data

Dim	mm				
Dim.	Min.	Тур.	Max.		
А	4.40		4.60		
b	0.61		0.88		
b1	1.14		1.70		
С	0.48		0.70		
D	15.25		15.75		
D1		1.27			
E	10		10.40		
е	2.40		2.70		
e1	4.95		5.15		
F	1.23		1.32		
H1	6.20		6.60		
J1	2.40		2.72		
L	13		14		
L1	3.50		3.93		
L20		16.40			
L30		28.90			
ØP	3.75		3.85		
Q	2.65		2.95		

REEL SPECIFICATION

P/N	PKG	QTY
L7812CV(MS)	TO-220	50/One tube 1000/a box of



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